

Ultrafast X-ray diffraction probe of terahertz field-driven soft mode dynamics in SrTiO₃

M. Kozina, ¹ T. van Driel, ¹ M. Chollet, ¹ T. Sato, ¹ J. M. Glownia, ¹ S. Wandel, ¹ M. Radovic, ^{2,3} U. Staub, ² and M. C. Hoffmann ¹

¹Linac Coherent Light Source, SLAC National Accelerator Laboratory, Menlo Park, California 94025, USA

(Received 29 March 2017; accepted 25 April 2017; published online 3 May 2017)

We use ultrafast X-ray pulses to characterize the lattice response of SrTiO₃ when driven by strong terahertz fields. We observe transient changes in the diffraction intensity with a delayed onset with respect to the driving field. Fourier analysis reveals two frequency components corresponding to the two lowest energy zone-center optical modes in SrTiO₃. The lower frequency mode exhibits clear softening as the temperature is decreased while the higher frequency mode shows slight temperature dependence. © 2017 Author(s). All article content, except where otherwise noted, is licensed under a Creative Commons Attribution (CC BY) license (http://creativecommons.org/licenses/by/4.0/). [http://dx.doi.org/10.1063/1.4983153]

The development of high peak-field sources of few-cycle terahertz (THz) pulses¹ has enabled experiments exploring THz-driven excitations in solids. While optical measurements (e.g., transient reflectivity or absorption,^{2,3} second harmonic generation,^{4,5} Faraday rotation,⁶ and impulsive stimulated Raman scattering⁷) are commonly employed to interrogate the THz-induced dynamics, the results only indirectly reveal any structural perturbations. On the other hand, the ultrafast X-ray sources including synchrotron slicing sources and X-ray free-electron lasers provide novel probes that can be used to explore structural dynamics via X-ray scattering.^{8–13} The combination of single-cycle THz excitation with ultrafast X-ray diffraction probe pulses allows direct tracking of atomic displacements within the unit cell when driven by an intense electromagnetic field. Because the X-ray pulses are short compared to the carrier-envelope-phase-stable THz pulse, it is possible to study the sample response on a sub-cycle time scale while the driving field is still present.

Recently, ultrafast THz fields have been proposed to drive domain switching in ferroelectric systems. 6,14,15 However, direct evidence of the concomitant ionic motion coupled to the domain flipping is lacking. Strontium titanate (SrTiO₃, STO) is a prototypical perovskite that is prevented from undergoing a ferroelectric phase transition at low temperature because of quantum fluctuations. 16,17 The similar structure of STO to the bulk perovskite ferroelectrics BaTiO₃ and PbTiO₃ (Ref. 18) suggests that this system may be used as a model case to explore the structural changes induced under excitation with a THz field compared to those that exhibit equilibrium ferroelectricity. Moreover, STO has several zone-center infrared (IR)-active phonon modes 19 within the bandwidth of single-cycle table-top THz radiation sources 1 that can be driven resonantly by intense THz pulses. Thus, STO provides an interesting case for probing field-driven structural dynamics.

We performed time-resolved X-ray diffraction measurements on a thin 100 nm film of STO pumped by single-cycle THz radiation. The X-ray diffraction measurements were performed at the XPP end station²⁰ of the Linac Coherent Light Source (LCLS) in monochromatic mode. The X rays were tuned to 9.5 keV (\sim 1 eV bandwidth) and were 20 fs FWHM in duration at 120 Hz repetition rate with a 120 μ m spot size. The arrival time of the X-ray pulses relative to the pumping THz radiation was corrected using a spectral encoding mechanism,²¹ so that the effective jitter between the X rays and THz was less than 50 fs. Our X-ray signal was recorded using an area detector (CSPAD 140 K).²² All X-ray diffraction intensity measurements were

²Swiss Light Source, Paul Scherrer Institut, 5232 Villigen PSI, Switzerland

³SwissFEL, Paul Scherrer Institut, 5232 Villigen PSI, Switzerland

collected at the top of the $(2\overline{2}5)$ diffraction peak for the STO film and integrated over a 2D projection of reciprocal space on the detector at fixed sample position. We show a schematic of the scattering geometry in Fig. 1(b).

We generated single-cycle p-polarized THz pulses at $120\,\mathrm{Hz}$ via optical rectification of $1.3\,\mu\mathrm{m}$, 50 fs pulses from an optical parametric amplifier (OPA) in 4-N,N-dimethylamino-4'-N'-methyl-stilbazolium 2,4,6- trimethylbenzenesulfonate (DSTMS).²³ The OPA was pumped by 800 nm radiation from a Ti:sapphire system (120 Hz, 25 mJ, 40 fs). The THz field was measured using electro-optic sampling (EOS) in a $100\,\mu\mathrm{m}$ GaP crystal at the sample position using as a probe a small fraction of the 800 nm light not used to pump the OPA. The peak THz field strength was $250\pm50\,\mathrm{kV/cm}$, and the central frequency was ~3 THz with significant bandwidth from 0.5–6.5 THz (see Fig. 2(b)). The THz beam was propagated in a dry-nitrogen environment except for a few cm of ambient air immediately before the sample to mitigate any THz absorption by water vapor. See Fig. 1(a) for a diagram of this setup.

The times of arrival of the X-ray and 800 nm pulses were established by carrying out an 800 nm-pump, X-ray probe experiment on a bismuth thin film in the exact location of the STO sample and under otherwise identical conditions. On pumping with an 800 nm femtosecond laser pulse, Bi exhibits a structural change manifest as a rapid drop in the scattering intensity of the (111) diffraction peak.²⁴ We measured this signal and resolved the initial drop to a resolution of 50 fs. The relative time of arrival of the THz and 800 nm pulses was then chosen via EOS, so that the peak of the THz field was coincident with the 800 nm pulse and hence the X-ray pulse to within our time resolution. This procedure allowed us to unambiguously compare the THz response of the sample with the incident THz field.

Our sample consisted of an epitaxial $100\,\mathrm{nm}$ STO film on a $(La_{0.3}Sr_{0.7})(Al_{0.65}Ta_{0.35})O_3$ (LSAT) substrate with the (001) peak out of plane. For details of the sample growth, see Ref. 25. The sample temperature was tuned from $105\,\mathrm{K}$ to $320\,\mathrm{K}$ using a cooled nitrogen gas flow (Oxford Instruments Cryojet 5). The gas temperature provides a lower bound for the sample temperature, which is at most $10\,\mathrm{K}$ higher. Values quoted below correspond to the gas temperature.

In Figure 2(a), we show the fractional change in scattering intensity $\Delta I/I$ of the $(2\bar{2}5)$ Bragg peak of the STO film at 120 K as a function of time delay between the THz pump (black) and X-ray probe (blue). We define the fractional change in scattering intensity $\Delta I/I = [I(t)-I_0]/I_0$, where I_0 is the value of the scattered intensity before the THz pulse has arrived and I(t) is the intensity at time delay t. The THz polarization within the film is primarily

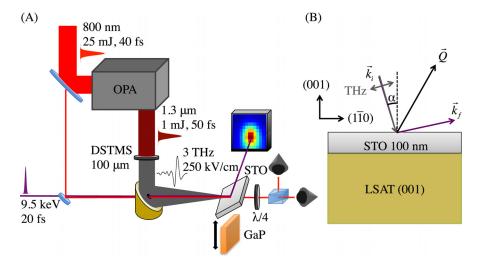


FIG. 1. (a) Schematic of experimental setup. Sample (SrTiO₃, STO) can be exchanged for GaP EOS crystal while maintaining interaction point. (b) Scattering geometry for the $(2\bar{2}5)$ reflection. The incoming X-ray wavevector (purple) is k_i and the diffracted wavevector is k_f . The vector Q (black) corresponds to the momentum transfer for the $(2\bar{2}5)$ reflection. The THz field (gray) comes in parallel with the X rays and is p-polarized. The angle $\alpha \sim 12^\circ$ is the angle of incidence of the X rays and THz with respect to the sample normal.

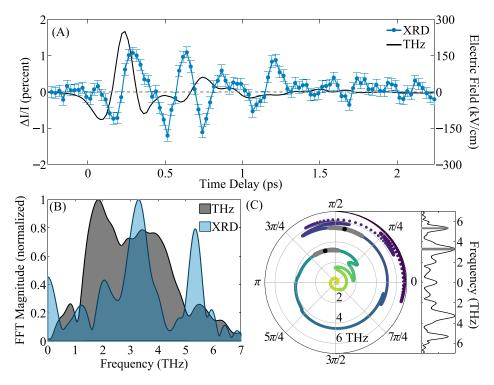


FIG. 2. (a) Electric field of THz excitation pump measured using electro-optic sampling (EOS) (black) and time-resolved change in $(2\overline{2}5)$ peak intensity at 120 K (blue). Error bars on the EOS data are smaller than the line width. (b) Magnitude of the FFT of the data in (a) with zero-padding; THz (black) and X-ray diffraction (XRD) (blue). (c) Phase difference between the THz and XRD signals as a function of FFT frequency (radial coordinate). The gray shaded regions highlight the two peaks of the XRD FFT magnitude shaded in the right subpanel, and the black dots mark the center frequency of each peak.

in-plane because of the large effective refractive index of the STO film and LSAT substrate complex. 2,26,27 In our scattering geometry, this is along the $[1\bar{1}0]$ direction. The short wavevector of the THz radiation will couple only to zone-center optical modes, which will modulate the structure factor of the diffraction peak. We specifically chose the $(2\bar{2}5)$ peak because its structure factor is particularly sensitive to ionic motion along the $[1\bar{1}0]$ direction.

Overlaid with the X-ray diffraction data is the electric field of the THz pump (black) measured from EOS. We see a clear time-delay between the arrival of the THz field and the onset of structural changes in the STO manifest as a change in diffraction intensity. Moreover, while the initial decrease and then increase in scattering intensity follow roughly the THz waveform, there are persistent oscillations in the X-ray diffraction signal after the THz pulse has passed. We attribute these to the excited zone-center optical phonons in the STO and describe in greater detail below.

In Fig. 2(b), we show the magnitude of the fast Fourier transform (FFT) of the THz and time-resolved X-ray data. We utilized zero-padding in order to better resolve the phase change between the two signals, as shown in Fig. 2(c). We observe two sharp peaks at frequencies consistent with known IR-active phonons at zone center 19 and label them TO₁ and TO₂. These peaks also explain the persistent oscillations in the X-ray scattering signal after the THz pulse has propagated out of the film. Because we are exciting on-resonance, we efficiently couple energy into both IR active modes, and so oscillations persist after the driving field has passed through the film. The phase difference between the THz pump and structural change is $\sim \pi/2$ (Fig. 2(c)) at each peak. This time delay between driving field and system response at resonance is to be expected for a driven damped harmonic oscillator model. The system response will delay the driving force by $\pi/2$ in agreement with our observations.

We assume that the THz couples only to the TO_1 and TO_2 modes and can estimate from the change in scattering intensity, the amount of motion of the ions within the STO unit cell. To calculate this, we begin with the time-dependent structure factor F(t).

$$F(t) = \sum_{j} f_{j} e^{i\mathbf{Q} \cdot \left[\mathbf{x}_{j} + \delta \mathbf{x}_{j}(t)\right]}.$$
 (1)

Here, \mathbf{Q} is the momentum transfer for the X-ray reflection and f_j , \mathbf{x}_j , and $\delta \mathbf{x}_j$ are the atomic scattering factor, the equilibrium coordinate, and the deviation from equilibrium for ion j, respectively. The sum runs over the five ions in the STO unit cell. The ionic motion will change the structure factor for the STO unit cell via $\delta \mathbf{x}_j$, which can be decomposed into projections along the TO₁ and TO₂ eigenvectors. Moreover, the fractional change in the square of the structure factor is equal to the fractional change in scattering intensity, $\Delta I/I = |F(t)|^2/|F(0)|^2 - 1$. Note that we ignore heating effects that would create an additional slow overall decay of the scattering intensity (e.g., strain waves and Debye-Waller factor modulation).

In Fig. 3(a), we plot the expected change in scattering intensity resulting from motion along either the TO_1 (solid blue) or TO_2 (dashed red) phonon eigenvector polarized parallel to the THz field (along the $[1\bar{1}0]$ direction). The gray shaded region corresponds to the largest intensity changes we observe in our scattering measurements. We show diagrams of the two phonon eigenvectors along the $[1\bar{1}0]$ direction in Fig. 3(b) (TO_1) and (c) (TO_2). The cubic symmetry of STO suggests that any ionic motion away from equilibrium will serve to only increase the scattering intensity of the (TO_2) peak, thus effectively rectifying the signal. However, the finite imaginary contribution to the atomic scattering factors shifts the minimum to a non-zero displacement, enabling measurements for low ionic motion to remain in a linear regime. Larger displacements will lead to a non-linear regime in the diffraction measurement (independent of any sample nonlinearity) that can lead to harmonics of the oscillation frequency, as we move towards the nonlinear portion of the parabola in Fig. 3(a).

As a first approximation, we assume that the motion of the ions is either along only the TO_1 eigenvector or the TO_2 eigenvector. From the two curves in Fig. 3(a), we can see that our maximal X-ray scattering intensity change of -1.2% corresponds to ~ 0.01 Å (TO_1 mode only) or ~ 0.003 Å (TO_2 mode only) motion of the Ti ion along [$1\bar{1}0$]. In reality, the actual motion will be a linear combination of these two eigenvectors. We require measurements of additional independent Bragg reflections to better differentiate the relative contribution of the

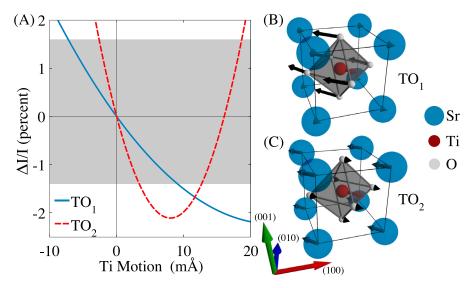


FIG. 3. (a) Calculated change in scattering intensity versus Ti motion along $[1\bar{1}0]$ for two different eigenvectors, TO₁ and TO₂. The shaded patch in gray corresponds to the regime of changes in intensity we measure in Fig. 2(a). (b) Illustration of TO₁ eigenvector polarized along $[1\bar{1}0]$. Sr, Ti, and O are blue, red, and gray, respectively. (c) Illustration of TO₂ eigenvector polarized along $[1\bar{1}0]$. Compare Ref. 28 for mode eigenvectors.

two eigenvectors; however, we can use the value for the TO₁ motion of the Ti ion as an upper bound.

The upper bound of the Ti motion is \sim 0.01 Å, or 0.25%, of the lattice parameter, similar to values reported elsewhere via THz time-domain spectroscopy.² This is about ten times smaller than the offset of the Ti ion in ferroelectric tetragonal BaTiO₃, which shifts along the ferroelectric polarization direction by 2% of the lattice constant.²⁹ Thus, while we are able to drive the Ti ions with the THz field, the required deviation for similar structural motion compared to equilibrium perovskite ferroelectrics has not been achieved.

In STO films on LSAT substrates, the low-frequency soft mode undergoes reduced softening as a function of temperature ^{19,30} compared to bulk STO. To explore the change in coupling between the STO film and the THz pump, we tuned the sample temperature from 105 K to 320 K. In Figure 4(a), we show the time-resolved change in scattering intensity as a function of temperature; in Figure 4(b), we show the magnitude of the Fourier transform of these data (not padded), along with the square root of a fit of the power spectrum to two Gaussian peaks. Each spectrum exhibits two peaks: one that varies strongly with temperature and the other that is nearly constant. The black lines are guides to the eye to highlight the temperature dependence of the central frequency of each peak. We identify the signal at the lower frequency as the soft mode TO₁, showing a clear reduction in frequency, as the temperature is lowered. The other peak is close to the known value of the next zone-center IR active phonon mode TO₂ in STO and shows weak temperature dependence in agreement with IR measurements.¹⁹

In Figure 5, we summarize the temperature dependence of the various fit parameters from the power spectra. Overlaid with our results (solid markers) are values from IR measurements taken on 107 nm STO films on LSAT from Ref. 19 (hollow markers). We find that the low frequency peak goes from 3.3 THz at 105 K to 3.80 THz at 270 K, in good agreement with the values reported from IR reflectivity¹⁹ and ellipsometry.³⁰ Moreover, the magnitude of the soft mode signal decreases with temperature, while the TO₂ mode increases (Fig. 5(b)) even though the THz driving field spectral content is flat over the soft mode frequency range. A similar shift in spectral weight has been observed in hyper-Raman measurements of bulk STO at higher temperatures and was there attributed to coupling between the TO₁ and TO₂ modes.³¹

The combination of excitation with single-cycle THz radiation and ultrafast X-ray diffraction expands the capabilities of THz spectroscopy. Because X-ray diffraction gives direct insight on the structural changes of a system, we can readily observe coupling between THz radiation and phonon modes. Using a THz-pump, X-ray probe measurement of STO, we were able to directly observe the softening of the low-frequency mode as a function of temperature. Moreover, because our measurement was taken in the time domain, we were able to observe

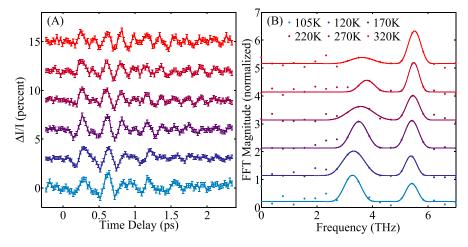


FIG. 4. (a) Time-resolved change in scattering intensity of the $(2\overline{2}5)$ peak after excitation with THz as a function of temperature. (b) Magnitude of Fourier transform of data in (a) overlaid with the square-root of a fit of the power spectrum to two Gaussian peaks. The dots are data and the solid lines are the resultant fit.

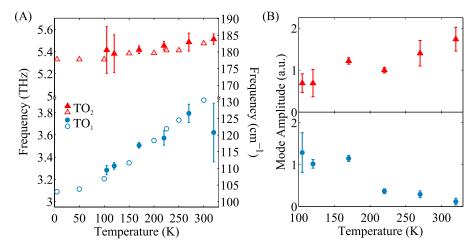


FIG. 5. Fit parameters from Fig. 4(b) as a function of temperature for each peak. The TO_1 mode (blue circles) is the low-frequency peak and the TO_2 mode (red triangles) is the high-frequency peak. Solid markers are from this work while hollow markers are from Ref. 19. (a) Central frequency of peak. (b) Magnitude of the peak normalized to the peak value for TO_1 at 120 K. Error bars are 95% confidence intervals from the fitting routine.

the phase shift between the THz field and the response of the STO system, reiterating the capability of time-domain measurements to study non-equilibrium processes as they happen.

Use of the Linac Coherent Light Source (LCLS), SLAC National Accelerator Laboratory, is supported by the U.S. Department of Energy, Office of Science, Office of Basic Energy Sciences, under Contract No. DE-AC02-76SF00515. M.K. and M.C.H. are supported by the U.S. Department of Energy, Office of Science, Office of Basic Energy Sciences, under Award No. 2015-SLAC-100238-Funding. U.S. acknowledges the support from the National Center of Competence in Research, Molecular Ultrafast Science and Technology (NCCR MUST), a research instrument of the Swiss National Science Foundation (SNSF).

¹H. A. Hafez, X. Chai, A. Ibrahim, S. Mondal, D. Férachou, X. Ropagnol, and T. Ozaki, J. Opt. 18, 093004 (2016).

²I. Katayama, H. Aoki, J. Takeda, H. Shimosato, M. Ashida, R. Kinjo, I. Kawayama, M. Tonouchi, M. Nagai, and K. Tanaka, Phys. Rev. Lett. 108, 097401 (2012).

³G. L. Dakovski, W. S. Lee, D. G. Hawthorn, N. Garner, D. Bonn, W. Hardy, R. Liang, M. C. Hoffmann, and J. J. Turner, Phys. Rev. B 91, 220506(R) (2015).

⁴F. Chen, J. Goodfellow, S. Liu, I. Grinberg, M. C. Hoffmann, A. R. Damodaran, Y. Zhu, P. Zalden, X. Zhang, I. Takeuchi, A. M. Rappe, L. W. Martin, H. Wen, and A. M. Lindenberg, Adv. Mater. 27, 6371 (2015).

⁵T. Morimoto, T. Miyamoto, H. Yamakawa, T. Terashige, T. Ono, N. Kida, and H. Okamoto, Phys. Rev. Lett. 118, 107602 (2017).

⁶T. Kampfrath, A. Sell, G. Klatt, A. Pashkin, S. Mährlein, T. Dekorsy, M. Wolf, M. Fiebig, A. Leitenstorfer, and R. Huber, Nat. Photonics 5, 31 (2011).

⁷B. S. Dastrup, J. R. Hall, and J. A. Johnson, Appl. Phys. Lett. **110**, 162901 (2017).

⁸J. J. Turner, G. L. Dakovski, M. C. Hoffmann, H. Y. Hwang, A. Zarem, W. F. Schlotter, S. Moeller, M. P. Minitti, U. Staub, S. Johnson, A. Mitra, M. Swiggers, P. Noonan, G. I. Curiel, and M. Holmes, J. Synchrotron Radiat. 22, 621 (2015).

⁹A. Cavalleri, S. Wall, C. Simpson, E. Statz, D. W. Ward, K. A. Nelson, M. Rini, and R. W. Schoenlein, Nature **442**, 664 (2006).

¹⁰T. Kubacka, J. A. Johnson, M. C. Hoffmann, C. Vicario, S. de Jong, P. Beaud, S. Grübel, S.-W. Huang, L. Huber, L. Patthey, Y.-D. Chuang, J. J. Turner, G. L. Dakovski, W.-S. Lee, M. P. Minitti, W. Schlotter, R. G. Moore, C. P. Hauri, S. M. Koohpayeh, V. Scagnoli, G. Ingold, S. L. Johnson, and U. Staub, Science 343, 1333 (2014).

¹¹S. Grübel, J. A. Johnson, P. Beaud, C. Dornes, A. Ferrer, V. Haborets, L. Huber, T. Huber, A. Kohutych, T. Kubacka, M. Kubli, S. O. Mariager, J. Rittmann, J. I. Saari, Y. Vysochanskii, G. Ingold, and S. L. Johnson, e-print arXiv:1602.05435v1.

¹² A. X. Gray, M. C. Hoffmann, J. Jeong, N. P. Aetukuri, D. Zhu, H. Y. Hwang, N. C. Brandt, H. Wen, A. J. Sternbach, S. Bonetti, A. H. Reid, R. Kukreja, C. Graves, T. Wang, P. Granitzka, Z. Chen, D. J. Higley, T. Chase, E. Jal, E. Abreu, M. K. Liu, T.-C. Weng, D. Sokaras, D. Nordlund, M. Chollet, H. Lemke, J. Glownia, M. Trigo, Y. Zhu, H. Ohldag, J. W. Freeland, M. G. Samant, J. Berakdar, R. D. Averitt, K. A. Nelson, S. S. P. Parkin, and H. A. Dürr, e-print arXiv:1601.07490v2.

¹³F. Chen, Y. Zhu, S. Liu, Y. Qi, H. Y. Hwang, N. C. Brandt, J. Lu, F. Quirin, H. Enquist, P. Zalden, T. Hu, J. Goodfellow, M.-J. Sher, M. C. Hoffmann, D. Zhu, H. Lemke, J. Glownia, M. Chollet, A. R. Damodaran, J. Park, Z. Cai, I. W. Jung, M. J. Highland, D. A. Walko, J. W. Freeland, P. G. Evans, A. Vailionis, J. Larsson, K. A. Nelson, A. M. Rappe, K. Sokolowski-Tinten, L. W. Martin, H. Wen, and A. M. Lindenberg, Phys. Rev. B 94, 180104 (2016).

- ¹⁴T. Qi, Y.-H. Shin, K.-L. Yeh, K. A. Nelson, and A. M. Rappe, Phys. Rev. Lett. **102**, 247603 (2009).
- ¹⁵T. Kampfrath, K. Tanaka, and K. A. Nelson, Nat. Photonics 7, 680 (2013).
- ¹⁶K. A. Müller and H. Burkard, Phys. Rev. B **19**, 3593 (1979).
- ¹⁷W. Zhong and D. Vanderbilt, Phys. Rev. B **53**, 5047 (1996).
- ¹⁸R. E. Cohen, Nature **358**, 136 (1992).
- ¹⁹D. Nuzhnyy, J. Petzelt, S. Kamba, T. Yamada, M. Tyunina, A. K. Tagantsev, J. Levoska, and N. Setter, J. Electroceram.
- 22, 297 (2009).

 20, 297 (2009).

 20, Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Alonso-Mori, M. Cammarata, D. Damiani, J. Defever, J. T. Delor, Y. Feng, J. M. Glownia, J. B. Langton, D. Chollet, R. Chollet, R S. Nelson, K. Ramsey, A. Robert, M. Sikorski, S. Song, D. Stefanescu, V. Srinivasan, D. Zhu, H. T. Lemke, and D. M. Fritz, J. Synchrotron Radiat. 22, 503 (2015).
- ²¹M. R. Bionta, H. T. Lemke, J. P. Cryan, J. M. Glownia, C. Bostedt, M. Cammarata, J.-C. Castagna, Y. Ding, D. M. Fritz, A. R. Fry, J. Krzywinski, M. Messerschmidt, S. Schorb, M. L. Swiggers, and R. N. Coffee, Opt. Express 19, 21855
- (2011). ²²S. Herrmann, S. Boutet, B. Duda, D. Fritz, G. Haller, P. Hart, R. Herbst, C. Kenney, H. Lemke, M. Messerschmidt, J. Pines, A. Robert, M. Sikorski, and G. Williams, Nucl. Instrum. Methods Phys. Res., Sect. A 718, 550 (2013).
- ²³M. Stillhart, A. Schneider, and P. Günter, J. Opt. Soc. Am. B **25**, 1914 (2008).
- ²⁴K. Sokolowski-Tinten, C. Blome, J. Blums, A. Cavalleri, C. Dietrich, A. Tarasevitch, I. Uschmann, E. Förster, M. Kammler, M. Horn-von-Hoegen, and D. von der Linde, Nature 422, 287 (2003).
- ²⁵M. Kozina, M. Pancaldi, C. Bernhard, T. Van Driel, J. M. Glownia, P. Marsik, C. A. F. Vaz, D. Zhu, S. Bonetti, U. Staub, and M. C. Hoffmann, Appl. Phys. Lett. **110**, 081106 (2017). ²⁶T. Kiwa and M. Tonouchi, Jpn. J. Appl. Phys., Part 2 **40**, L38 (2001).
- ²⁷T. N. Nunley, T. I. Willett-Gies, J. A. Cooke, F. S. Manciu, P. Marsik, C. Bernhard, and S. Zollner, J. Vac. Sci. Technol. A 34, 051507 (2016).

 ²⁸R. A. Cowley, Phys. Rev. 134, A981 (1964).
- ²⁹G. H. Kwei, A. C. Lawson, S. J. L. Billinge, and S. W. Cheong, J. Phys. Chem. **97**, 2368 (1993).
- ³⁰P. Marsik, K. Sen, J. Khmaladze, M. Yazdi-Rizi, B. P. P. Mallett, and C. Bernhard, Appl. Phys. Lett. 108, 052901 (2016).
- ³¹V. N. Denisov, B. N. Mavnn, V. B. Podobedov, and J. F. Scott, J. Raman Spectrosc. 14, 276 (1983).